NSN 5962-01-092-2733

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View Online at https://aerobasegroup.com/nsn/5962-01-092-2733 **Body Length:** Between 0.747 inches and 0.815 inches **Body Width:** 0.310 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 556.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and bipolar and w/storage and programmable and programmed and w/enable and w/disable and high speed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 30003-247as-c2615 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life:

Demilitarization: Voc. domil/mli

Unit Of Measure:

N/a

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